TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# **TC7MH367FK,TC7MH368FK**

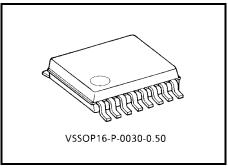
HEX Bus Buffer

TC7MH367FK Non-Inverted, 3-State Outputs TC7MH368FK Inverted, 3-State Outputs

The TC7MH367FK and TC7MH368FK are advanced high speed CMOS HEX bus buffers fabricated with silicon gate  $C^2MOS$  technology.

They achieve the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

They contain six buffers; four buffers are controlled by an enable input ( $\overline{G}1$ ), and the other two buffers are controlled by another enable input ( $\overline{G}2$ ). The outputs of each buffer group are enabled when  $\overline{G}1$  and/or  $\overline{G}2$  inputs are held low; if held high, these outputs are in a high impedance state.



Weight: 0.02 g (typ.)

The TC7MH367FK is a non-inverting output type, while the TC7MH368FK is an inverting output type.

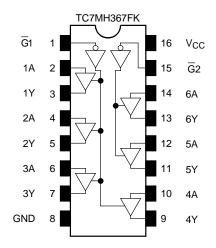
An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

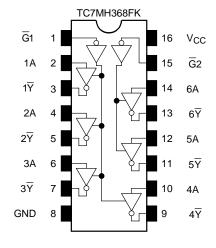
#### Features

- High speed:  $t_{pd} = 3.8 \text{ ns} (typ.) (V_{CC} = 5 \text{ V})$
- Low power dissipation:  $I_{CC} = 4 \ \mu A \ (max) \ (Ta = 25^{\circ}C)$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: VCC (opr) =  $2 \sim 5.5$  V
- Low noise:  $V_{OLP} = 0.8 V (max)$
- Pin and function compatible with 74ALS367/368

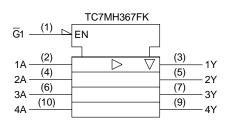
# <u>TOSHIBA</u>

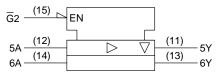
#### Pin Assignment (top view)





#### **IEC Logic Symbol**



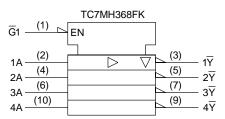


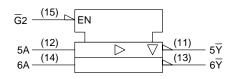
#### **Truth Table**

Inp	uts	Outputs				
G	А	Y (367)	<del>-</del> <u>Y</u> (368)			
L	L	L	Н			
L	Н	Н	L			
Н	Х	Z	Z			

X: Don't care

Z: High impedance





## **Maximum Ratings**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5~7.0	V
DC input voltage	V <sub>IN</sub>	-0.5~7.0	V
DC output voltage	V <sub>OUT</sub>	$-0.5 \sim V_{CC} + 0.5$	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	I <sub>OK</sub>	±20	mA
DC output current	IOUT	±25	mA
DC V <sub>CC</sub> /ground current	ICC	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T <sub>stg</sub>	-65~150	°C

# **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0~5.5	V
Input voltage	V <sub>IN</sub>	0~5.5	V
Output voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40~85	°C
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 $\pm$ 0.3 V)	ns/V
input lise and fair time	ui/uv	0~20 (V <sub>CC</sub> = 5 $\pm$ 0.5 V)	115/ V

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics		Symbol	Symbol Test Condi		Condition		Ta = 25°C			Ta = -40~85°C	
Characte	ISUCS	Symbol	Symbol Test Condition		$V_{CC}(V)$	Min	Тур.	Max	Min	Max	Unit
High level			—		2.0	1.50	_	_	1.50	_	V
		VIH			3.0~5.5	$V_{CC} \times 0.7$	_		$V_{CC} \times 0.7$		
input voltage					2.0			0.50	_	0.50	v
	Low level V <sub>IL</sub>		3.0~5.5		_	$V_{CC} \times 0.3$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.3 \end{array}$			
				I <sub>OH</sub> = -50 μA	2.0	1.9	2.0		1.9	_	
			V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		3.0	2.9	3.0		2.9	_	
Output voltage	High level	V <sub>OH</sub>			4.5	4.4	4.5		4.4	—	
				$I_{OH} = -4 \text{ mA}$	3.0	2.58	—		2.48	—	
				$I_{OH} = -8 \text{ mA}$	4.5	3.94	—		3.80	—	
oulput voltago			V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0	0.1		0.1	
					3.0	_	0	0.1	—	0.1	
	Low level	VoL			4.5	_	0	0.1	—	0.1	
				$I_{OL} = 4 \text{ mA}$	3.0	_		0.36		0.44	
			$I_{OL} = 8 \text{ mA}$	4.5	_	_	0.36		0.44		
3-state output of	f-state current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		5.5	_	_	±0.25	_	±2.50	μΑ
Input leakage cu	rrent	I <sub>IN</sub>	$V_{IN} = 5.5 \text{ V or GND}$		0~5.5			±0.1		±1.0	μΑ
Quiescent supply	y current	Icc	$V_{IN} = V_{CC} \text{ or } GND$		5.5		_	4.0	_	40.0	μΑ

#### AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol Test Condition				Ta = 25°C			Ta = -4	Unit	
	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Min	Max	Unit	
			3.3 ± 0.3	15	_	5.9	8.3	1.0	10.0	
Propagation delay time	t <sub>pLH</sub>		5.5 ± 0.5	50	_	8.4	11.8	1.0	13.5	ns
(TC7MH367)	t <sub>pHL</sub>		5.0 ± 0.5	15		4.1	5.9	1.0	7.0	113
			5.0 ± 0.5	50		5.6	7.9	1.0	9.0	
			3.3 ± 0.3	15		5.3	7.5	1.0	9.0	
Propagation delay time	t <sub>pLH</sub>		5.5 ± 0.5	50		7.8	11.0	1.0	12.5	ns
(TC7MH368)	tpHL			5.0 ± 0.5	15		3.8	5.5	1.0	6.5
			5.0 ± 0.5	50		5.3	7.5	1.0	8.5	
	t <sub>pZL</sub> t <sub>pZH</sub>	$R_L = 1 \ k\Omega$	$3.3 \pm 0.3$	15		6.8	10.5	1.0	12.5	ns
3-state output enable time				50		9.3	14.0	1.0	16.0	
3-state output enable time				15		4.8	7.2	1.0	8.5	
				50		6.3	9.2	1.0	10.5	
3-state output disable time	t <sub>pLZ</sub>	$R_{I} = 1 k\Omega$	$\textbf{3.3}\pm\textbf{0.3}$	50		9.9	13.6	1.0	15.5	ns
5-state output disable time	t <sub>pHZ</sub>	NL - 1 K22	$5.0\pm0.5$	50		6.3	9.2	1.0	10.5	113
Output to output skew	t <sub>osLH</sub>	(Note1)	$\textbf{3.3}\pm\textbf{0.3}$	50			1.5		1.5	ns
	t <sub>osHL</sub>	(Note I)	$5.0\pm0.5$	50			1.0	_	1.0	113
Input capacitance	C <sub>IN</sub>	-	_		_	4	10	_	10	pF
Output capacitance	C <sub>OUT</sub>	_	_		_	6	_			pF
Power dissipation capacitance	C <sub>PD</sub>			(Note2)	_	19	_	_	_	pF

Note1: Parameter guaranteed by design.

 $t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$ 

Note2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

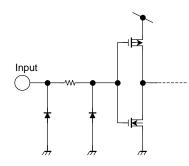
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per bit)}$ 

## Noise Characteristics (Input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics	Symbol	Test Condition	_	Ta = 25°C		Unit
Characteristics	Symbol	Test Condition	$V_{CC}(V)$	Тур.	Limit	Unit
Quiet output maximum dynamic $V_{OL}$	V <sub>OLP</sub>	$C_L = 50 \text{ pF}$	5.0	0.4	0.8	V
Quiet output minimum dymnamic $V_{OL}$	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.4	-0.8	V
Minimum high level dynamic input voltage $V_{IH}$	VIHD	$C_L = 50 \text{ pF}$	5.0	_	3.5	V
Maximum low level dynamic input voltage $V_{IL}$	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0		1.5	V

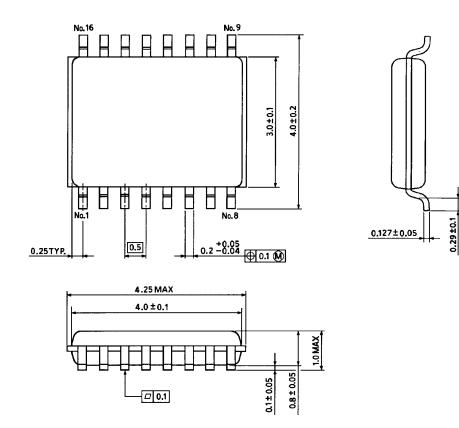
## Input Equivalent Circuit



#### **Package Dimensions**

VSSOP16-P-0030-0.50

Unit : mm



Weight: 0.02 g (typ.)

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